

# SK25DGDL12T4 T



**SEMITOP®4**

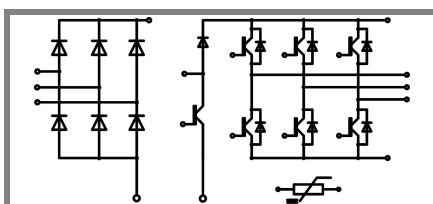
3-phase bridge rectifier +  
brake chopper + 3-phase  
bridge inverter

SK 25 DGDL 12T4 T

## Features

- One screw mounting module
- Fully compatible with SEMITOP®1,2,3
- Improved thermal performances by aluminium oxide substrate
- Trench4 IGBT technology
- CAL4 technology free-wheeling diode
- Integrated NTC temperature sensor

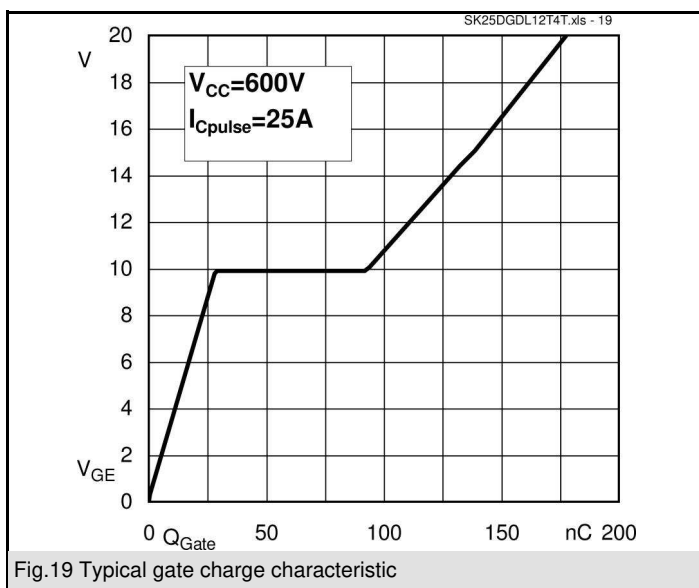
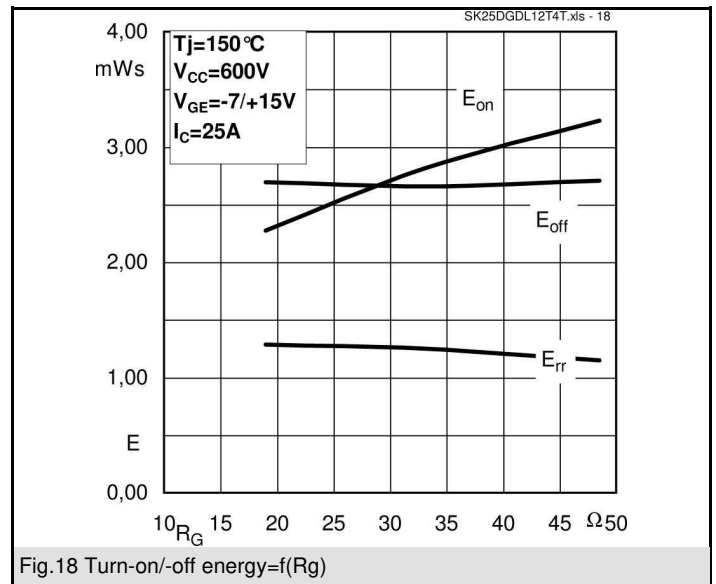
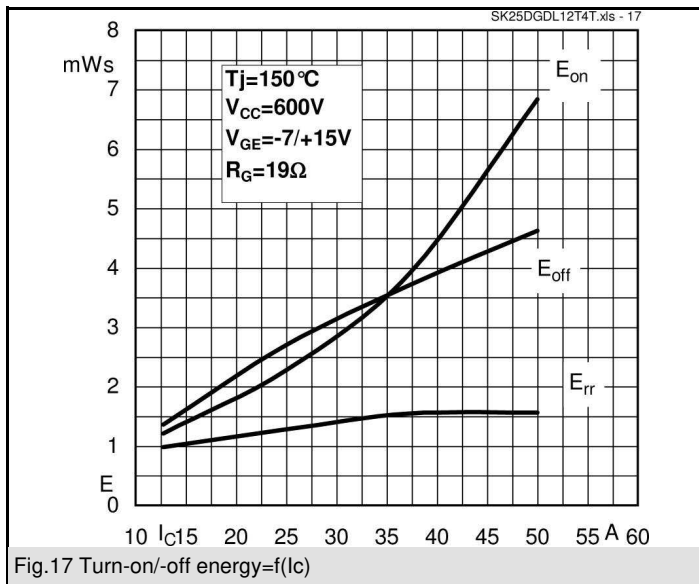
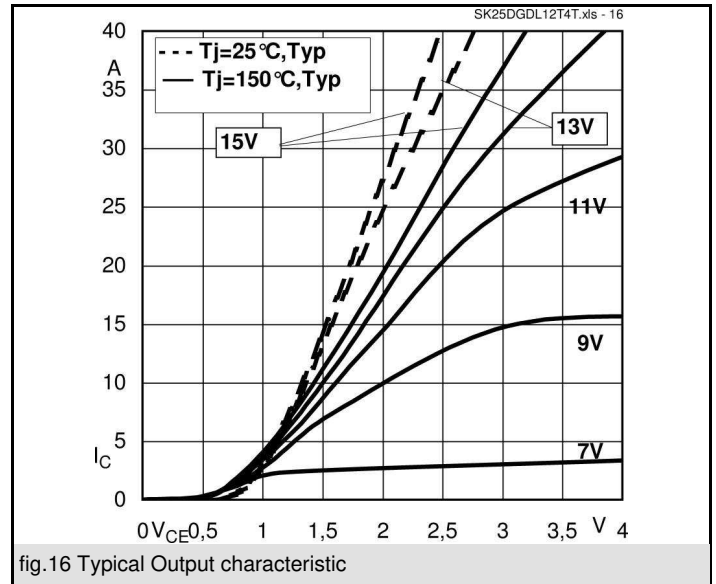
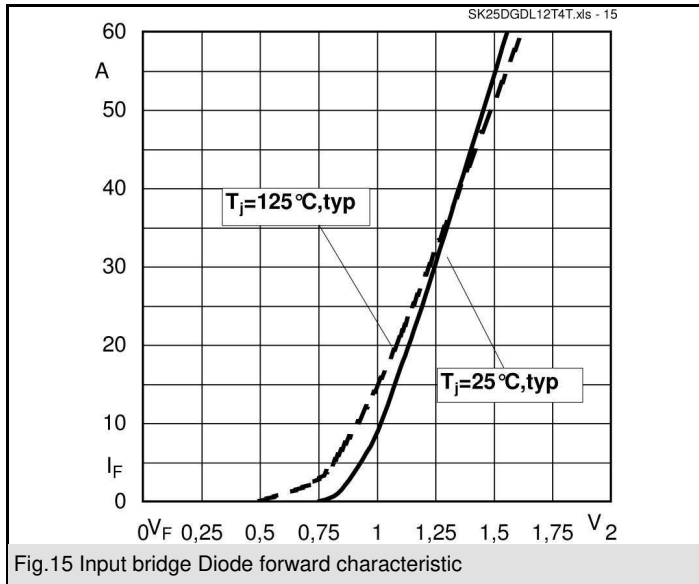
1)  $V_{CE,sat}$ ,  $V_F$  = chip level value

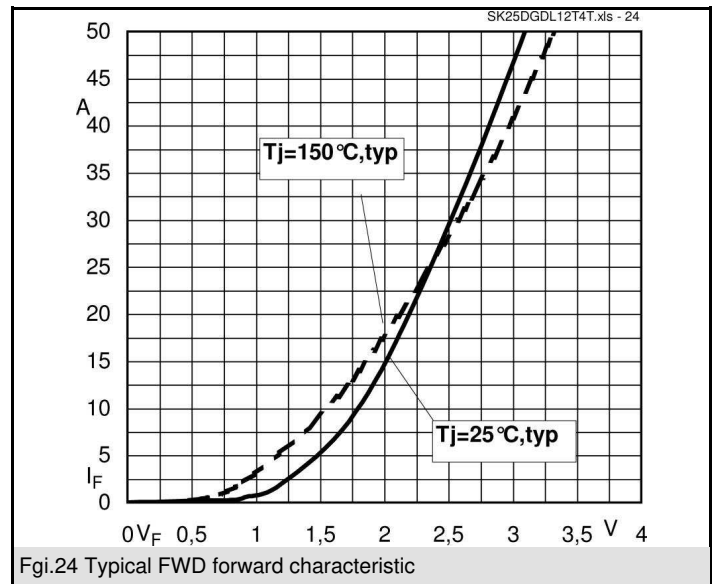
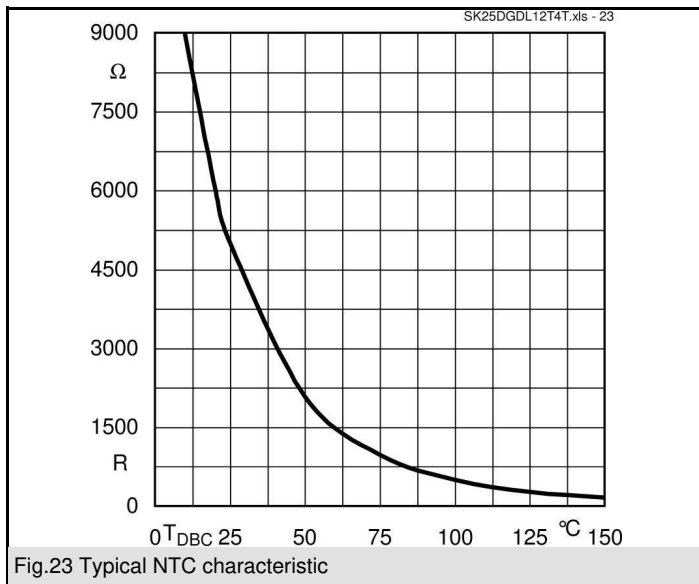
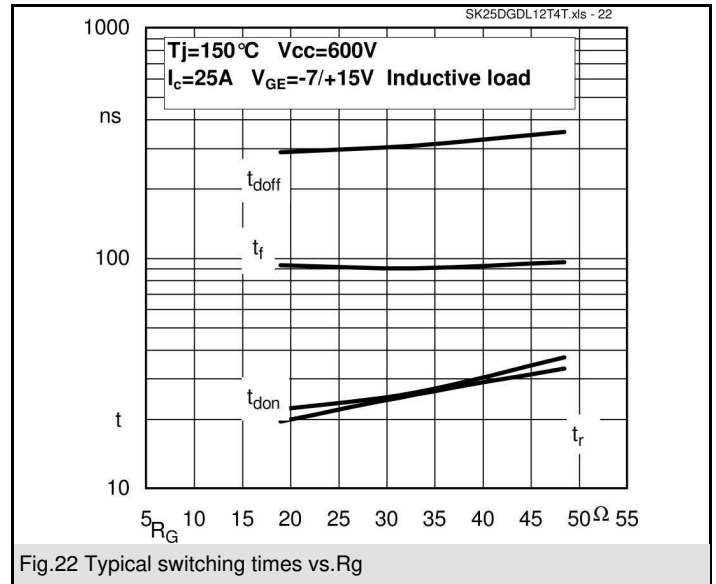
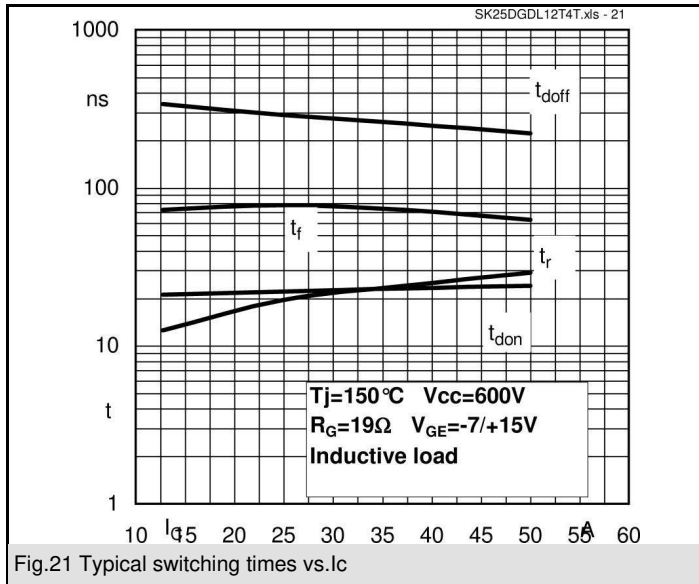


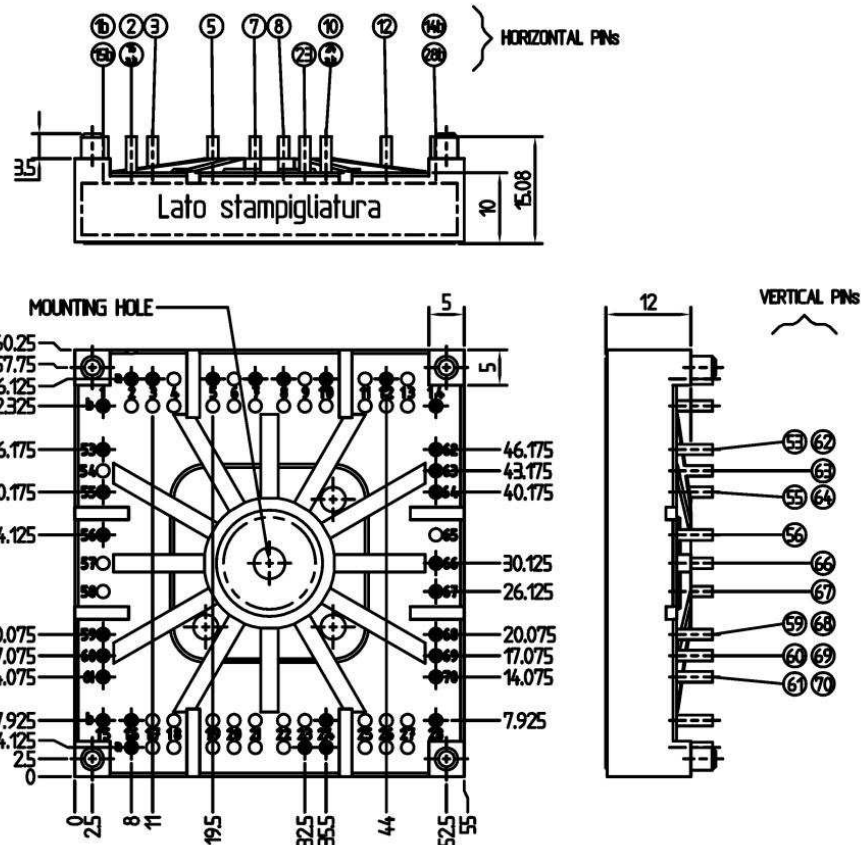
DGDL - T

Absolute Maximum Ratings		Ts = 25 °C, unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT - Inverter,Chopper</b>			
$V_{CES}$		1200	V
$I_C$	$T_s = 25 (70) ^\circ C$	45 (36)	A
$I_{CRM}$	$I_{CRM} = 3 \times I_{Cnom}$ , $t_p = 1 \text{ ms}$	75	A
$V_{GES}$		$\pm 20$	V
$T_j$		-40 ... +175	$^\circ C$
<b>Diode - Inverter,Chopper</b>			
$I_F$	$T_s = 25 (70) ^\circ C$	30 (24)	A
$I_{FRM}$	$I_{FRM} = 2 \times I_{Fnom}$ , $t_p = 1 \text{ ms}$	75	A
$T_j$		-40 ... +150	$^\circ C$
<b>Rectifier</b>			
$V_{RRM}$		1600	V
$I_F$	$T_s = 70 ^\circ C$	46	A
$I_{FSM} / I_{TSM}$	$t_p = 10 \text{ ms}$ , $\sin 180^\circ$ , $T_j = 25 ^\circ C$	370	A
$I_t^2$	$t_p = 10 \text{ ms}$ , $\sin 180^\circ$ , $T_j = 25 ^\circ C$	684	A <sup>2</sup> s
$T_j$		-40 ... +175	$^\circ C$
$T_{sol}$	Terminals, 10 s	260	$^\circ C$
$T_{stg}$		-40 ... +125	$^\circ C$
$V_{isol}$	AC, 1 min. / 1 s	2500 / 3000	V

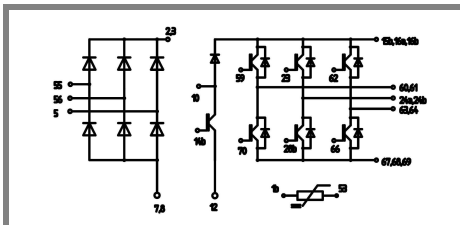
Characteristics		Ts = 25 °C, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
<b>IGBT - Inverter</b>					
$V_{CEsat}$	$I_C = 25 \text{ A}$ , $T_j = 25 (150) ^\circ C$		1,85 (2,25)	2,05 (2,45)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 1 \text{ mA}$	5	5,8	6,5	V
$V_{CE(TO)}$	$T_j = 25 ^\circ C (150) ^\circ C$		1,1 (1)	1,3 (1,2)	V
$r_T$	$T_j = 25 ^\circ C (150) ^\circ C$		30 (50)		m $\Omega$
$C_{ies}$	$V_{CE} = 25 \text{ V}$ , $V_{GE} = 0 \text{ V}$ , $f = 1 \text{ MHz}$		1,43		nF
$C_{oes}$	$V_{CE} = 25 \text{ V}$ , $V_{GE} = 0 \text{ V}$ , $f = 1 \text{ MHz}$		0,11		nF
$C_{res}$	$V_{CE} = 25 \text{ V}$ , $V_{GE} = 0 \text{ V}$ , $f = 1 \text{ MHz}$		0,085		nF
$R_{th(j-s)}$	per IGBT		0,96		K/W
$t_{d(on)}$	under following conditions		22		ns
$t_r$	$V_{CC} = 600 \text{ V}$ , $V_{GE} = \pm 15 \text{ V}$		19,5		ns
$t_{d(off)}$	$I_C = 25 \text{ A}$ , $T_j = 150 ^\circ C$		288		ns
$t_f$	$R_{Gon} = R_{Goff} = 19 \Omega$		77,5		ns
$E_{on}$	inductive load		2,27		mJ
$E_{off}$			2,7		mJ
<b>Diode - Inverter,Chopper</b>					
$V_F = V_{EC}$	$I_F = 25 \text{ A}$ , $T_j = 25 (150) ^\circ C$		2,4 (2,45)	2,75 (2,8)	V
$V_{(TO)}$	$T_j = 25 ^\circ C (150) ^\circ C$		1,3 (0,9)	1,5 (1,1)	V
$r_T$	$T_j = 25 ^\circ C (150) ^\circ C$		44 (62)	50 (68)	m $\Omega$
$R_{th(j-s)}$	per diode		1,7		K/W
$I_{RRM}$	under following conditions		-		A
$Q_{rr}$	$I_F = \text{A}$ , $V_R = \text{V}$		-		$\mu\text{C}$
$E_{rr}$	$V_{GE} = 0 \text{ V}$ , $T_j = 150 ^\circ C$ $di_F/dt = - \text{A}/\mu\text{s}$		-		mJ
<b>Diode - Rectifier</b>					
$V_F$	$I_F = 25 \text{ A}$ , $T_j = 25 ( ) ^\circ C$		1,1		V
$V_{(TO)}$	$T_j = 150 ^\circ C$		0,8		V
$r_T$	$T_j = 150 ^\circ C$		13		m $\Omega$
$R_{th(j-s)}$	per diode		1,25		K/W
<b>Temperatur sensor</b>					
$R_{ts}$	5 %, $T_r = 25 (100) ^\circ C$		5000(493)		$\Omega$
<b>Mechanical data</b>					
w			60		g
$M_s$	Mounting torque		2,6		Nm







Case T 75 (Suggested hole diameter for the solder pins in the circuit board: 2mm. Suggested hole diameter for the mounting pins in the circuit board: 3,6mm )



Case T 75 (pin without letter refers to row "a", unless otherwise specified)

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

### \*IMPORTANT INFORMATION AND WARNINGS

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